D961, OCTOBER 1979 - REVISED SEPTEMBER 1990

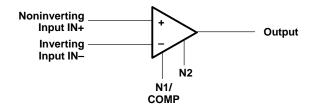
- Low Input Currents
- Low Input Offset Parameters
- Frequency and Transient Response Characteristics Adjustable
- Short-Circuit Protection
- Offset-Voltage Null Capability
- No Latch-Up
- Wide Common-Mode and Differential Voltage Ranges
- Same Pin Assignments as uA709
- Designed to be Interchangeable with National Semiconductor LM101A and LM301A

description

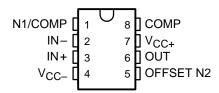
The LM101A, LM201A, and LM301A are highperformance operational amplifiers featuring very low input bias current and input offset voltage and current to improve the accuracy of highimpedance circuits using these devices. The high common-mode input voltage range and the absence of latch-up make these amplifiers ideal for voltage-follower applications. The devices are protected to withstand short circuits at the output. The external compensation of these amplifiers allows the changing of the frequency response (when the closed-loop gain is greater then unity) for applications requiring wider bandwidth or higher slew rate. A potentiometer may be connected between the offset-null inputs (N1 and N2), as shown in Figure 7, to null out the offset voltage.

The LM101A is characterized for operation over the full military temperature range of -55° C to 125° C, the LM201A is characterized for operation from -25° C to 85° C, and the LM301A is characterized for operation from 0° C to 70° C.

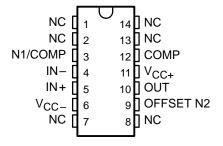
symbol



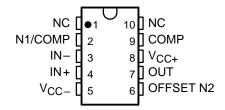
D, JG, OR P PACKAGE (T0P VIEW)



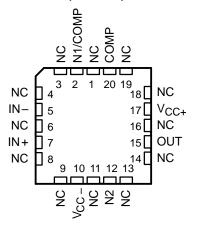
LM101A W FLAT PACKAGE (T0P VIEW)



LM101A U FLAT PACKAGE (T0P VIEW)



LM101A FK CHIP-CARRIER PACKAGE (T0P VIEW)



NC - No internal connection



AVAILABLE OPTIONS

	.,	PACKAGE							
TA	V _{IO} MAX at 25°C	SMALL OUTLINE	CHIP CARRIER	CERAMIC DIP	PLASTIC DIP	FLAT PACK	FLAT PACK		
		(D)	(FK)	(JG)	(P)	(U)	(W)		
0°C to 70°C	7.5 mV	LM301AD	_	_	LM301AP	_	_		
−25°C to 85°C	2 mV	LM201AD	-	_	LM201AP	_	_		
−55°C to 125°C	2 mV	LM101AD	LM101AFK	LM101AJG	LM101AP	LM101AU	LM101AW		

The D package is available taped and reeled. Add the suffix R to the device type, (i.e., LM301ADR).

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		LM101A	LM201A	LM301A	UNIT		
Supply voltage V _{CC+} (see Note 1)	22	22	18	V			
Supply voltage V _{CC} – (see Note 1)		-22	-22	-18	V		
Differential input voltage (see Note 2)		±30	±30	±30	V		
Input voltage (either input, see Notes 1 and 3)		±15 ±15		±15	V		
Voltage between either offset null terminal (N1/N2) and V _{CC} -	-0.5 to 2 -0.5 to 2		-0.5 to 2	V			
Duration of output short-circuit (see Note 4)	unlimited	unlimited	unlimited				
Continuous total power dissipation		See Dissipation Rating Table					
Operating free-air temperature range	-55 to 125	-25 to 85	0 to 70	°C			
Storage temperature range	-65 to 150	-65 to 150	-65 to 150	°C			
Case temperature for 60 seconds: FK package	260			°C			
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG, U, or W package	300			°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package	260	260	260	°C		

- NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC+} and V_{CC-}
 - 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 - 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 - 4. The output may be shorted to ground or either power supply. For the LM101A only, the unlimited duration of the short-circuit applies at (or above) 125°C case temperature or 75°C free-air temperature. For the LM201A only, the unlimited duration of the short-circuit applies at (or below) 85°C case temperature or 75°C free-air temperature.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \le 25^{\circ} \mbox{\scriptsize C}$	DERATING	DERATE	T _A = 70°C	T _A = 85°C	T _A = 125°C
	POWER RATING	FACTOR	ABOVE TA	POWER RATING	POWER RATING	POWER RATING
D	500 mW	5.8 mW/°C	64°C	464 mW	377 mW	145 mW
FK	500 mW	11.0 mW/°C	105°C	500 mW	500 mW	275 mW
JG	500 mW	8.4 mW/°C	90°C	500 mW	500 mW	210 mW
Р	500 mW	8.0 mW/°C	87°C	500 mW	500 mW	200 mW
U	500 mW	5.4 mW/°C	57°C	432 mW	351 mW	135 mW
W	500 mW	8.0 mW/°C	87°C	500 mW	500 mW	200 mW

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V _{CC+}	5	18	V
Supply voltage, V _{CC} _	-5	-18	



electrical characteristics at specified free-air temperature, C_C = 30 pF (see Note 5)

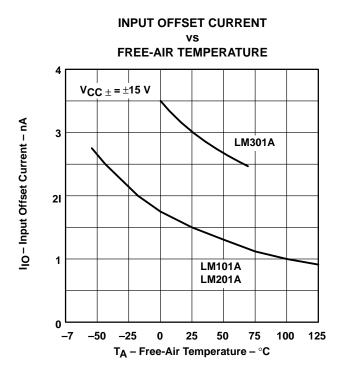
DADAMETED		TEST CONDITIONS†		LM101A, LM201A		LM301A		LINUT		
	PARAMETER	TEST CONDITIONS!		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
\/.a	land offertualtens	V- 0	25°C		0.6	2		2	7.5	mV
VIO	Input offset voltage	VO = 0	Full range			3			10	IIIV
ανιο	Average temperature coefficient of input offset voltage	V _O = 0	Full range		3	15		6	30	μV/°C
li o	Input offset current		25°C		1.5	10		3	50	
ΙΟ			Full range			20			70	nA
		$T_A = -55^{\circ}C$ to $25^{\circ}C$			0.02	0.2				
ano.	Average temperature coefficient of	$T_A = 25^{\circ}C$ to MAX	(0.01	0.1				- A /00
αΙΙΟ	input offset current	$T_A = 0$ °C to 25°C						0.02	0.6	nA/°C
		$T_A = 25^{\circ}C$ to $70^{\circ}C$						0.01	0.3	
lin	Input bias current		25°C		30	75		70	250	<u> </u>
IB			Full range			100			300	nA
VICR	Common-mode input voltage range	See Note 6	Full range	±15			±12			V
	Maximum peak-to-peak output voltage swing	$V_{CC\pm} = \pm 15 \text{ V},$	25°C	24	28		24	28		V
.,		$R_L = 10 \text{ k}\Omega$	Full range	24			24			
VOPP		$V_{CC\pm} = \pm 15 \text{ V},$	25°C	20	26		20	26		
		$R_L = 2 k\Omega$	Full range	20			20			
AVD	Large-signal differential voltage amplification	$V_{CC\pm} = \pm 15 \text{ V},$ $V_{CC\pm} = \pm 10 \text{ V},$	25°C	50	200		25	200		V/mV
/ VD		amplification	$R_L \ge 2 k\Omega$	Full range	25			15		
rį	Input resistance		25°C	1.5	4		0.5	2		МΩ
	Common-mode rejection ratio	V _{IC} = V _{ICR} min	25°C	80	98		70	90		
CMRR			Full range	80			70			dB
le = 1 = -	Supply voltage rejection ratio		25°C	80	98	i	70	96		JD.
ksvr	$(\Delta V_{CC}/\Delta V_{IO})$		Full range	80			70			dB
Icc	Supply current	No load, $V_O = 0$,	25°C		1.8	3		1.8	3	A
ICC	Supply current	See Note 6	MAX		1.2	2.5		-		mA

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range for LM101A is -55°C to 125°C, for LM201A is -25°C to 85°C, and for LM301A is 0°C to 70°C.

NOTES: 5. Unless otherwise noted, $V_{CC\pm}$ = ± 5 V to ± 20 V for LM101A and LM201A, and $V_{CC\pm}$ = ± 5 V to ± 15 V for LM301A. All typical values are at $V_{CC\pm}$ = ± 15 V.

^{6.} For LM101A and LM201A, $V_{CC\pm} = \pm 20 \text{ V}$. For LM301A, $V_{CC\pm} = \pm 15 \text{ V}$.

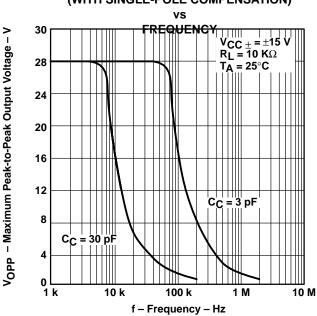
TYPICAL CHARACTERISTICS



INPUT BIAS CURRENT FREE-AIR TEMPERATURE 100 $V_{CC \pm} = \pm 15 V$ 80 IB - Input Bias Current - nA LM301A 60 40 LM101A LM201A 20 0 └ -75 -50 -25 0 25 100 125 50 75 T_A - Free-Air Temperature - °C

Figure 1





OPEN-LOOP LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION

Figure 2

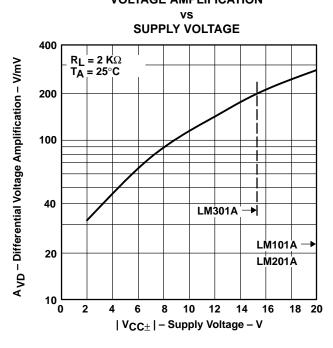
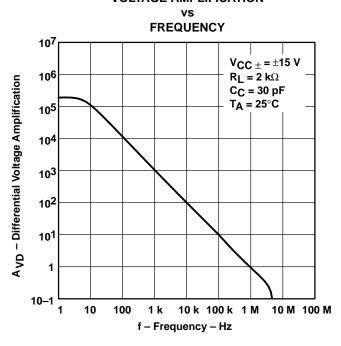


Figure 3 Figure 4

TYPICAL CHARACTERISTICS

OPEN-LOOP LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION



VOLTAGE-FOLLOWER
LARGE-SIGNAL PULSE RESPONSE

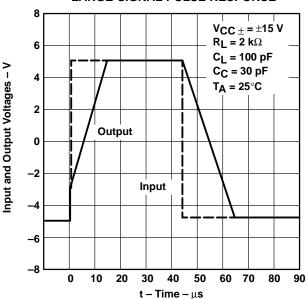
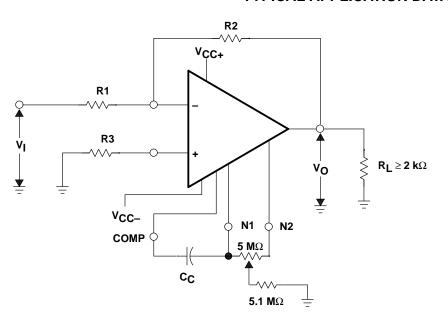


Figure 5 Figure 6

TYPICAL APPLICATION DATA



$$\frac{V_O}{V_I} = -\frac{R2}{R1}$$

$$C > \frac{R1 \cdot 30}{R1}$$

$$C_{\rm C} \, \geq \, \frac{R1 \, \cdot \, 30 \, \, pF}{R1 \, + \, R2}$$

$$R3 = \frac{R1 \cdot R2}{R1 + R2}$$

Figure 7. Inverting Circuit with Adjustable Gain, Single-Pole Compensation, and Offset Adjustment



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